DONOSTIA INTERNATIONAL PHYSICS CENTER







Quantum Wires Coupled to Dissipative Enviroments MA Cazalilla

Centro de Física de Materiales, Centro Mixto CSIC-UPV/EHU & Donostia International Physics Center, San Sebastian, Spain

In collaboration with:

F Sols (U Complutense Madrid, Spain)

F Guinea (ICMM-CSIC Madrid, Spain)Phys. Rev. Lett. <u>97</u>, 076401 (2006)E Malatsetxeberria (CFM, San Sebastian, Spain)

Workshop on Correlations and Coherence in Quantum Matter, Évora (Portugal), November 10-14

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How to pin a Wigner Crystal Using a Metallic Gate MA Cazalilla

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Workshop on Correlations and Coherence in Quantum Matter, Évora (Portugal), November 10-14 Give me a 1D wire! Single Wall Carbon Nanotubes (SWCNT's) Armchair CNT: Perhaps the cleanest 1D metal...







飯島さん (lijima)

朝永 (Tomonaga)-Luttinger liquid (TLL) behavior



Yet, a fluctuating crystal...

Can we pin this fluctuating Wigner Crystal ?

Of course, disorder will do it, but ...



The electron density wave will 'adapt' to the disorder and we will end up seeing the disorder itself (the localized electron waves) but not the Wigner crystal.
[Boundaries or isolated impurities will lead to (exponentially, at finite T) decaying Friedel oscillations]

We want a true ground state with true long range order

How about gates?

Tuners of the chemical potential in mesoscopic systems



But can a gate pin the ID Wigner Crystal?

However, the screening due to gates is dynamic



Model of the gate

Integrate out gate's degrees of freedom F Guinea PRL <u>53</u> (1984); F Sols & F Guinea, PRB <u>36</u> (1987)

$$S_{\rm D} = \frac{1}{2\hbar} \int d\tau d\mathbf{r} \, d\tau' d\mathbf{r}' \, \rho(\mathbf{r}, \tau) V_{\rm scr}(\mathbf{r}, \mathbf{r}', \tau - \tau') \rho(\mathbf{r}', \tau')$$
$$V_{\rm scr}(\mathbf{r}, \mathbf{r}', \tau) = -\frac{1}{\hbar} \langle V_{\rm C}(\mathbf{r}, \tau) V_{\rm C}(\mathbf{r}', 0) \rangle; \quad V_{\rm C}(\mathbf{r}, \tau) = \int d\mathbf{r}' \, \frac{\rho_{\rm gate}(\mathbf{r}', \tau)}{4\pi\epsilon |\mathbf{r} - \mathbf{r}'|}$$

Static screening part: image potential

$$V_{\rm scr}(x,z_0,\tau) \simeq W_{\rm scr}(x,z_0)\delta(\tau) + \frac{S(x,z_0)}{|\tau|^2} \quad |\tau| \gg \tau_c \sim \omega_p^{-1}$$

Ohmic dissipation: e.g. particle-hole excitations in the gate

$$\rho(\mathbf{r}) = \rho(x)\delta(y)\delta(z - z_0) \xrightarrow{} \mathbf{z}_0 \uparrow$$

$$\rho(x) = \frac{1}{\pi}\partial_x\phi(x) + \mathcal{A}\cos\left[2\phi(x) + 2k_F x\right] + \cdots \qquad \text{gate}$$



Model of ID wire

Use bosonization $\rho(x) = \frac{1}{\pi} \partial_x \phi(x) + \mathcal{A} \cos \left[2\phi(x) + 2k_F x \right] + \cdots$

$$\begin{split} S[\phi] &= S_0[\phi] + S_D[\phi], \\ S_0[\phi] &= \frac{1}{2\pi g} \int dx d\tau \left[\frac{1}{v} \left(\partial_\tau \phi \right)^2 + v \left(\partial_x \phi \right)^2 \right], \quad v_F = vg, \\ S_D[\phi] &= S_{FD}[\phi] + S_{BD}[\phi], \frac{\text{Forward}(\text{FD}) \quad q \approx 0, \\ \text{Backward}(\text{BD}) \quad q \approx Q = 2p^2 k_F \\ S_{FD}[\phi] &= \int \frac{dq d\omega}{(2\pi)^2} f(q, \omega) \left| \phi(q, \omega) \right|^2 \\ f(q, \omega) \sim \left\{ \begin{array}{c} \ln(1/q)q^2 |\omega| \Rightarrow \text{Irrelevant} (3\text{D gate}), \\ q |\omega| \Rightarrow \text{Marginal} (2\text{D gate}), \end{array} \right\} \\ S_{BD}[\phi] &= -\frac{\eta}{\pi} \int dx d\tau d\tau' \frac{\cos 2p \left[\phi(x, \tau) - \phi(x, \tau') \right]}{|\tau - \tau'|^{s+1}} \\ \text{Obmic s=1} \end{split}$$

$$\begin{aligned} & \text{Low-energy effective field theory} \\ S[\phi] &= S_0[\phi] + S_D[\phi], \\ S_0[\phi] &= \frac{1}{2\pi g} \int dx d\tau \left[\frac{1}{v_{\text{pl}}} \left(\partial_\tau \phi \right)^2 + v_{\text{pl}} \left(\partial_x \phi \right)^2 \right], \\ S_D[\phi] &= -\frac{\alpha}{\pi v_{\text{pl}} \tau_c} \int dx d\tau d\tau' \, \frac{\cos 2p \left[\phi(x,\tau) - \phi(x,\tau') \right]}{|\tau - \tau'|^{1+s}} \end{aligned}$$

$$n_{\rm ch} = p^2$$

p = 1 spin polarized e⁻ $p = \sqrt{2}$ spinful e⁻ (g < 1/3) p = 2 nanotubes (g < 1/5)

Weak-coupling RG $= -4p^2 g v \alpha, \quad \frac{dg}{d\ell} = -4p^2 g^2 \alpha, \\ \alpha = (v\tau_c) \tau_c^{1-s} \eta \\ = \left(2-s-2p^2 g\right),$ dv $\overline{d\ell}$ $d\alpha$ $d\ell$ $\ell = \log(\omega_c/T)$ ** QCP at $g^* = (2-s)/2p^2$ and $\alpha^* = 0$ with z = 1 !!

Critical phase (Tomonaga-Luttinger liquid) for $g > g^*$ and $\alpha \to 0^+$ Re $\sigma(\omega > 0) \sim \alpha \mathcal{D}\left(\frac{\omega}{\omega_c}\right)^{\mu-4}$ $\mu = 2p^2g + s + 1$ Strong coupling (SC) phase (?) for $g < g^*$ and $\alpha \to 0^+$ Correlation length near QCP $\frac{\xi_1}{a} \approx e^{-\pi/(2-s)p\sqrt{\alpha-\alpha_c}}$

SCHA or how to get insights into the SC phase

Replace the non-linear term

$$S_{BD}[\phi] = -\frac{\eta}{\pi} \int dx d\tau d\tau' \frac{\cos 2p \left[\phi(x,\tau) - \phi(x,\tau')\right]}{|\tau - \tau'|^2}$$

by a quadratic action

$$S_{\rm SCHA}[\phi] = -\frac{1}{2} \int dx d\tau d\tau' \, \Sigma(\tau - \tau') \left[\phi(x, \tau) - \phi(x, \tau')\right]^2 \quad \Sigma(\tau \gg \tau_c) \simeq \frac{\tilde{\eta}}{\pi |\tau|^2}$$

Optimize free energy: $\tilde{\eta} \sim a \, (\eta a)^{rac{1}{1-2p^2g}}$

Drude-like conductivity
$$\sigma(\omega) = \frac{i\mathcal{D}}{\omega + i/\tau_d}, \quad \tau_d^{-1} \sim v_F \tilde{\eta}$$

True CDW order

$$\langle \rho(x)\rho(0)\rangle_{Q=2pk_F} \approx a^{-1}\langle e^{2ip\phi(x)}e^{-2ip\phi(0)}\rangle \to \text{const.}$$

"Seizing" of the vacuum $as |x| \rightarrow +\infty$ J Kogut and L Susskind PRD <u>II</u> (1975) AH Castro-Neto, CC Chamon & C Nayak PRL <u>79</u> (1997)

Understanding why it will get pinned...



- The gate acts like a measurement apparatus, which performs a continuous measurement of the wire density. • The quantum wire is very susceptible of measurements at the Fourier component $q = 2 n_{ch} k_F$
- Invoking the Quantum Zeno Effect that then

$$\langle \rho(q = 2n_{\rm ch}k_F) \rangle = {\rm const.}$$



Dynamic screening = dissipation $t = t_0$ $t = t_1 > t_0$

Estimates (for a nanotube):

$$\alpha \approx g \left(\frac{k_F^{\text{Gate}}}{k_F}\right)^2 \frac{e^{-16k_F z_0}}{\sigma_{\text{Gate}}}$$



<u>Hint</u>: Use a highly resistive 2D metal, or better, a granular system as gate (no metallic screening at q = 0)

Is this the whole story?

Large N: yet another QCP...

Introduce unit vector: $\mathbf{n}(x,\tau) = (\cos 2p\phi(x,\tau), \sin 2p\phi(x,\tau))$ O(2) dissipative NLoM $G_0^{-1}(q,\omega) = \eta |\omega| + \kappa_p [(\omega/v)^2 + q^2]$ $S[\mathbf{n},\lambda] = \frac{1}{2} \int \frac{dqd\omega}{(2\pi)^2} \, G_0^{-1}(q,\omega) |\mathbf{n}(q,\omega)|^2 + \frac{i}{2} \int dx d\tau \lambda(x,\tau) \left[\mathbf{n}^2(x,\tau) - 1\right],$ S Sachdev, A V Chubukov & A Sokol PRB <u>51</u> (1995), S Pankov et al PRB <u>69</u> (2004) $O(2) \rightarrow O(N)$ + Large N limit: saddle point for $\lambda = -i\kappa_n \xi^{-2}$ $N \int \frac{dq d\omega}{(2\pi)^2} \frac{1}{n|\omega| + \kappa_n [(\omega/v)^2 + q^2 + \xi^{-2}]} = 1$ ** Another QCP with z = 2 (z = 1.97(3) MC) $\xi^{-1} \sim (\eta_c - \eta)^{\nu}$ $\nu = 1 \ (\nu \simeq 0.689(6) \ (MC))$

MC calculations (dissipative XY model) P Werner, M Troyer & S Sachdev J Phys Soc Jpn Supl. <u>74</u> (2005)

Large N: yet another phase... $\Phi(x,\tau) = a \langle \rho(x,\tau) \rho(0) \rangle_{Q=2pk_F}$ $\Phi(x,\tau) \simeq \langle e^{2ip\phi(x,\tau)}e^{-2ip\phi(0)} \rangle = \langle \mathbf{n}(x,\tau) \cdot \mathbf{n}(0,0) \rangle$ Disordered phase $\eta < \eta_c \Rightarrow \xi^{-1} \neq 0$ $\xi^{-1} \sim (\eta_c - \eta)^{\nu}$ $\Phi(0,\tau) \sim \frac{1}{\tau^2}, \quad \Phi(x,0) \sim \frac{e^{-|x|/\xi}}{|\xi^{-1}x|}$ "puddles" = single dissipative rotor $C_0(x,0) \sim \frac{1}{|x|},$ Ordered phase $\Phi(x,\tau) = N_0^2 [1 + C_0(x,\tau)]$ (same structure as SCHA) $\left| \xleftarrow{p} \right| p = \frac{2\pi}{Q}$ $C_0(0,\tau) \sim \frac{1}{\sqrt{|\tau|}}$

Expansion about the uncoupled rotor limit

$$S[\varphi] = \sum_{m=1}^{M} \left[\int_{0}^{\hbar\beta} d\tau \frac{1}{2C} \left(\frac{d\varphi_{m}(\tau)}{d\tau} \right)^{2} - \frac{\alpha}{\pi} \int_{0}^{\hbar\beta} d\tau d\tau' K(\tau - \tau') \cos \left[\varphi_{m}(\tau) - \varphi_{m}(\tau') \right] \right]$$

$$-K \int d\tau \cos \left[\varphi_{m}(\tau) - \varphi_{m+1}(\tau) \right].$$

Small

$$K(\tau) = (\pi/\hbar\beta)^{2} |\sin (\pi\tau/\hbar\beta)|^{-2}$$

$$K(\tau) = (\pi/\pi c)^{2} \qquad \mathcal{A}$$

Uncoupled rotor (exact): $\langle e^{i\varphi_m(\tau)}e^{-i\varphi_m(0)}\rangle = \left(\frac{1}{\hbar\beta}\right) \frac{1}{|\sin(\pi\tau/\hbar\beta)|^2}$ [H. Spohn and W. Zwerger J. Stat. Phys. <u>94</u> (1999)]

Perturbation theory in K is non-singular, e.g. free energy and

$$\langle e^{i\varphi_N(0)}e^{-i\varphi_1(0)}\rangle = \left(\frac{e^{-x_N/\xi_c}}{x_N/a_0}\right), \quad \xi_c^{-1} = \ln(\mathcal{A}K\tau_c)/a_0$$

Care with $\alpha = 0$ limit: avoiding KT requires including a Berry phase

$$S_{\text{Berry}} = iV_0 \sum_m \int_0^{\hbar\beta} d\tau \, \dot{\varphi}_m(\tau)$$

Schematic phase diagram



α

Schematic phase diagram SWCNT + Gate

